VS-EBU8006HF4

Vishay Semiconductors

Ultrafast Soft Recovery Diode, 80 A FRED Pt[®]



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PowerTab®

PRODUCT SUMMARY				
Package	PowerTab [®]			
I _{F(AV)}	80 A			
V _R	600 V			
V _F at I _F	1.53 V			
t _{rr} (typ.)	46 ns			
T _J max.	175 °C			
Diode variation	Single die			

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- · Screw mounting only
- AEC-Q101 gualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V _R		600	V
Continuous forward current	I _{F(AV)}	T _C = 113 °C	80	٨
Single pulse forward current	I _{FSM}	$T_{C} = 25 \ ^{\circ}C$	750	A
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 200 μA	600	-	-	
		I _F = 80 A	-	1.25	1.53	v
Forward voltage	V _F	I _F = 80 A, T _J = 125 °C	-	1.13	1.35	
		I _F = 80 A, T _J = 175 °C	-	1.07	1.25	
Deverse legisere environt		$V_R = V_R$ rated	-	-	8	μA
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	0.5	mA
Junction capacitance	CT	V _R = 600 V - 39 -		-	pF	
Series inductance	Ls	Measured lead to lead 5 mm from package body - 3.5 - n		nH		







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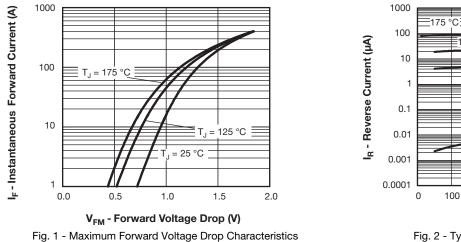
DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS		TYP.	MAX.	UNITS
		I_F = 1.0 A, dI _F /dt = 100 A/µs, V _R = 30 V		-	46	-	
Reverse recovery time t _{rr}	+	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	36	-	
	۲r	T _J = 25 °C		-	100	-	ns
	T _J = 125 °C		-	190	-		
Peak recovery current I _{RRM}	1	T _J = 25 °C	$I_{\rm F} = 50 \rm{A}$	-	10	-	А
	IRRM	T _J = 125 °C	V _R = 200 V dI _F /dt = 200 A/µs	-	17.5	-	~
Reverse recovery charge Qr	0	T _J = 25 °C		-	520	-	20
	Q _{rr}	T _J = 125 °C		-	1650	-	nC

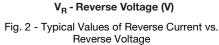
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.5	K/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	n,∕vv
Weight			-	-	5.02	g
weight			-	0.18	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)
Marking device		Case style PowerTab [®]		EBU8	006H	•

VS-EBU8006HF4

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300

200

125 °C

25 °C

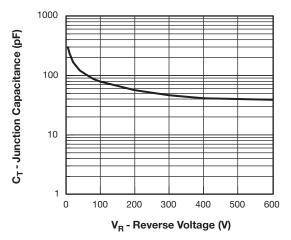
400

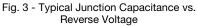
500

600

^o

150 °C





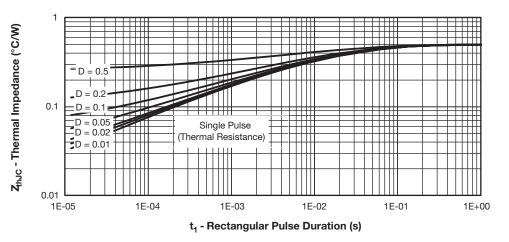
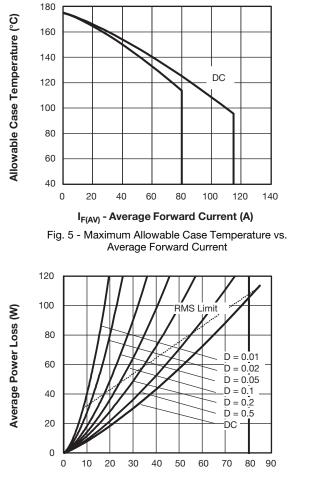


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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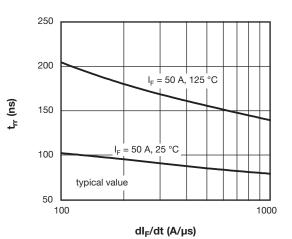


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Fig. 6 - Forward Power Loss Characteristics





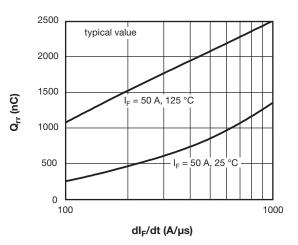


Fig. 8 - Typical Stored Charge vs. dl_F/dt

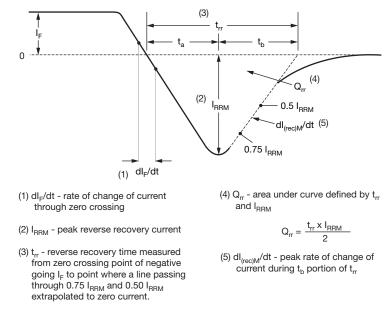


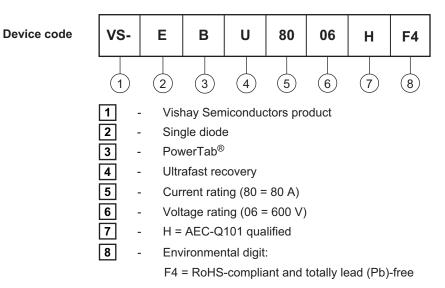
Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-EBU8006HF4	25	375	Antistatic plastic tube			

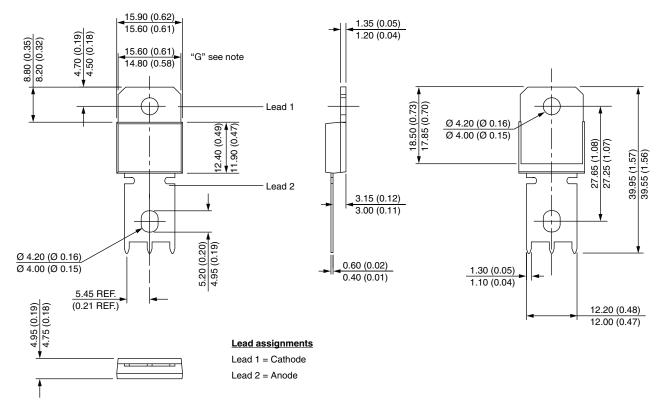
LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467		
Application note	www.vishay.com/doc?95179		



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DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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